BUK107-50DS

DESCRIPTION

Monolithic overload protected logic level power MOSFET in a surface mount plastic envelope, intended as a general purpose switch for automotive systems and other applications.

APPLICATIONS

General controller for driving

- lamps
- small motors
- solenoids

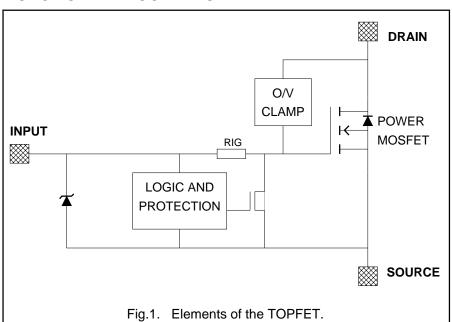
FEATURES

- Vertical power DMOS output stage
- Overload protected up to 85°C ambient
- Overload protection by current limiting and overtemperature sensing
- sensing
 Latched overload protection reset by input
- Input clamping suitable for pull-up resistor drive circuit
 Control of power MOSFET
- Control of power MOSFET and supply of overload protection circuits derived from input
- ESD protection on all pins
- Overvoltage clamping for turn off of inductive loads

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{DS}	Continuous drain source voltage	50	V
I _D	Continuous drain current	0.7	А
P _D	Total power dissipation	1.8	W
T _j	Continuous junction temperature	150	°C
R _{DS(ON)}	Drain-source on-state resistance	175	mΩ

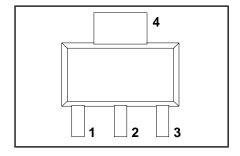
FUNCTIONAL BLOCK DIAGRAM



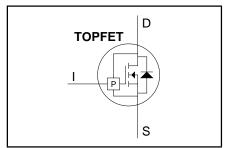
PINNING - SOT223

PIN	DESCRIPTION
1	input
2	drain
3	source
4	drain (tab)
	l

PIN CONFIGURATION



SYMBOL



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LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{DS}	Continuous drain source voltage ¹	-	-	50	V
I _D	Continuous drain current ²	-	-	self limiting	Α
l li	Continuous input current	clamping	-	3	mA
I _{IRM}	Non-repetitive peak input current	$t_{p} \le 1 \text{ ms}$	-	10	mA
P_{D}	Total power dissipation	$T_{amb}^r = 25 ^{\circ}C$	-	1.8	W
T _{stq}	Storage temperature	-	-55	150	°C
T _j	Continuous junction temperature	normal operation ³	-	150	°C

ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _C	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 kΩ	-	2	kV

OVERVOLTAGE CLAMPING LIMITING VALUES

At a drain source voltage above 50 V the power MOSFET is actively turned on to clamp overvoltage transients.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
E _{DSM}	Non-repetitive clamping energy	$I_b \le 25 ^{\circ}C; I_{DM} < I_{D(lim)};$	-	100	mJ
E _{DRM}	Repetitive clamping energy	inductive load $T_b \le 75$ °C; $I_{DM} = 50$ mA; $f = 250$ Hz	-	4	mJ

OVERLOAD PROTECTION LIMITING VALUES

With the protection supply provided via the input pin, TOPFET can protect itself from short circuit loads. Overload protection operates by means of drain current limiting and activating the overtemperature protection.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{DDP}	Protected drain source supply voltage	I _I = 1.5 mA	-	35	V
		$V_{IS} = 6 V$	-	16	V

OVERLOAD PROTECTION CHARACTERISTICS

TOPFET switches off to protect itself when there is an overload fault condition. It remains latched off until reset by the input.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Overload protection					
$I_{D(lim)}$	Drain current limiting	$I_{i} = 1.5 \text{ mA}$	0.7	1.1	1.5	Α
$T_{j(TO)}$	Overtemperature protection Threshold junction temperature	only in drain current limiting I _I = 1.5 mA	100	130	160	°C

¹ Prior to the onset of overvoltage clamping. For voltages above this value, safe operation is limited by the overvoltage clamping energy.

² Refer to OVERLOAD PROTECTION CHARACTERISTICS.

³ Not in an overload condition with drain current limiting.

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Thermal resistance					
R _{th j-sp}	Junction to solder point		-	12	18	K/W
R _{th j-b}	Junction to board ¹	Mounted on any PCB	-	40	-	K/W
R _{th j-a}	Junction to ambient	Mounted on PCB of fig. 19	-	-	70	K/W

STATIC CHARACTERISTICS

T_b = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{(CL)DSS}	Drain-source clamping voltage	$V_{IS} = 0 \text{ V}; I_{D} = 10 \text{ mA}$	50	55	-	V
V _{(CL)DSS}	Drain-source clamping voltage	$V_{IS} = 0 \text{ V}; I_{DM} = 200 \text{ mA};$	-	56	70	V
		$t_p \le 300 \ \mu s; \ \delta \le 0.01$				
I _{DSS}	Off-state drain current	$V_{DS} = 45 \text{ V}; V_{IS} = 0 \text{ V}$	-	0.5	2	μΑ
I _{DSS}	Off-state drain current	$V_{DS} = 50 \text{ V}; V_{IS} = 0 \text{ V}$	-	1	20	μΑ
I _{DSS}	Off-state drain current	$V_{DS} = 40 \text{ V}; V_{IS} = 0 \text{ V}; T_{i} = 100 ^{\circ}\text{C}$	-	10	100	μΑ
R _{DS(ON)}	Drain-source on-state	$I_1 = 1.5 \text{ mA}; I_{DM} = 100 \text{ mA};$	-	125	175	mΩ
	resistance ²	$t_{p} \le 300 \ \mu s; \ \delta \le 0.01$				

INPUT CHARACTERISTICS

 $T_b = 25$ °C unless otherwise specified. The supply for the logic and overload protection is taken from the input. The input clamping is suitable for a drive circuit with a pull-up resistor.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
V _{IS(TO)}	Input threshold voltage	$V_{DS} = 5 \text{ V}; I_{D} = 1 \text{ mA}$		1.7	2.2	2.7	V
I _{IS}	Input supply current	normal operation;	$V_{IS} = 6 V$	-	550	750	μΑ
I _{ISL}	Input supply current	protection latched;	$V_{IS} = 5 V$	-	500	650	μΑ
			$V_{IS} = 3.5 \text{ V}$	-	250	400	μΑ
V _{ISR}	Protection latch reset voltage ³		-	1	2.2	3.5	V
$V_{(CL)IS}$	Input clamping voltage	$I_1 = 1.5 \text{ mA}$		6	7.5	-	V
R _{IG}	Input series resistance	to gate of power MOS	FET	-	33	-	kΩ

SWITCHING CHARACTERISTICS

 T_{amb} = 25 °C; resistive load R_L = 50 Ω ; adjust V_{DD} to obtain I_D = 250 mA; refer to test circuit and waveforms

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t _{d on}	Turn-on delay time	$V_{IS} = 0 \text{ V to } I_I = 1.5 \text{ mA}$	ı	4	ı	μs
t _r	Rise time		-	16	-	μs
t _{d off}	Turn-off delay time	$I_I = 1.5 \text{ mA to } V_{IS} = 0 \text{ V}$	-	3	-	μs
t _f	Fall time		-	6	-	μs

¹ Temperature measured 1.3 mm from tab.

² Continuous input voltage. The specified pulse width is for the drain current.

³ The input voltage below which the overload protection circuits will be reset.

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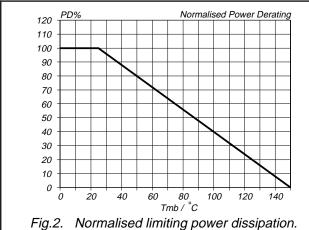


Fig.2. Normalised limiting power dissipation. $P_D\% = 100 \cdot P_D/P_D(25 \, ^{\circ}C) = f(T_{mb})$

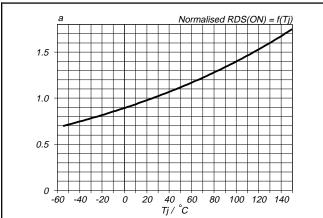
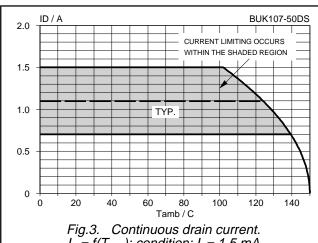


Fig.5. Normalised drain-source on-state resistance. $a = R_{DS(ON)}/R_{DS(ON)}25$ °C = $f(T_i)$; $I_D = 100$ mA; $I_I = 1.5$ mA



 $I_D = f(T_{amb})$; condition: $I_I = 1.5 \text{ mA}$

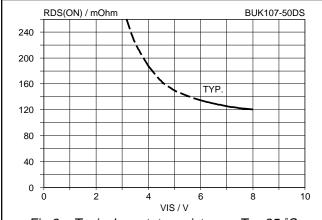


Fig.6. Typical on-state resistance, $T_j = 25$ °C. $R_{DS(ON)} = f(V_{IS})$; conditions: $I_D = 100$ mA, $t_p = 300$ μs

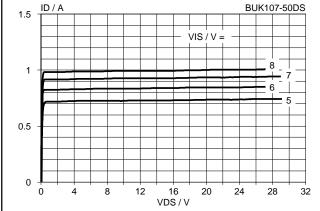


Fig.4. Typical on-state characteristics, $T_j = 25$ °C. $I_D = f(V_{DS})$; parameter V_{IS} ; $t_p = 300 \, \mu s$

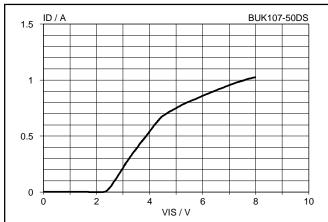


Fig.7. Typical transfer characteristics, $T_j = 25$ °C. $I_D = f(V_{IS})$; conditions: $V_{DS} = 10 \text{ V}$, $t_p = 300 \text{ }\mu\text{s}$

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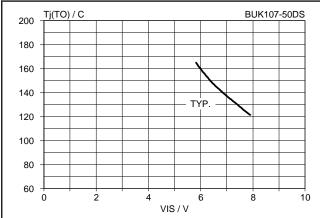
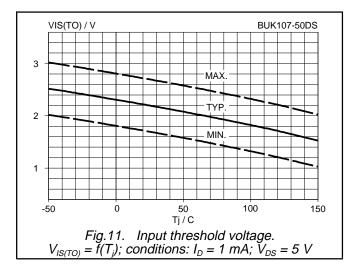


Fig.8. Typical overtemperature protection threshold. $T_{j(TO)} = f(V_{IS})$; condition: $V_{DS} = 10 \text{ V}$



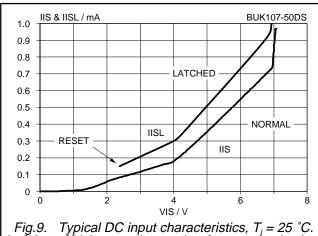


Fig.9. Typical DC input characteristics, $T_i = 25$ °C. I_{IS} & $I_{ISL} = f(V_{IS})$; normal operation & protection latched

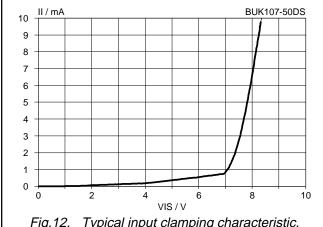
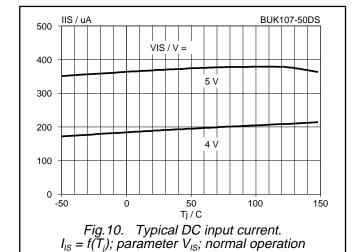


Fig.12. Typical input clamping characteristic. $I_1 = f(V_{IS})$; normal operation, $T_1 = 25$ °C.



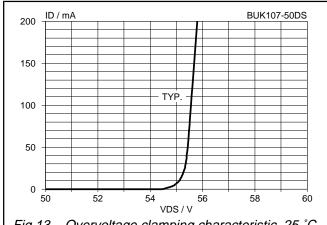


Fig.13. Overvoltage clamping characteristic, 25 °C. $I_D = f(V_{DS})$; conditions: $V_{IS} = 0$ V; $t_p \le 300 \, \mu s$

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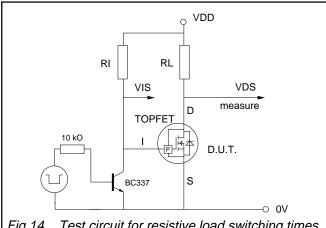
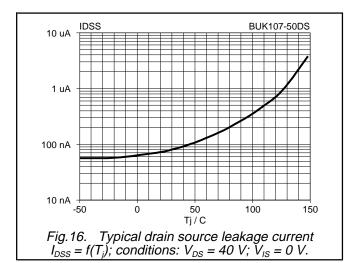


Fig.14. Test circuit for resistive load switching times. Select R_l to give $I_l = 1.5$ mA, ie 3.3 k Ω approx.



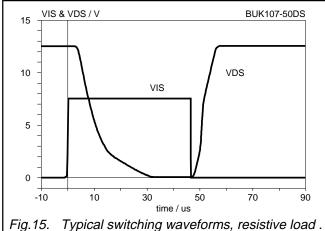
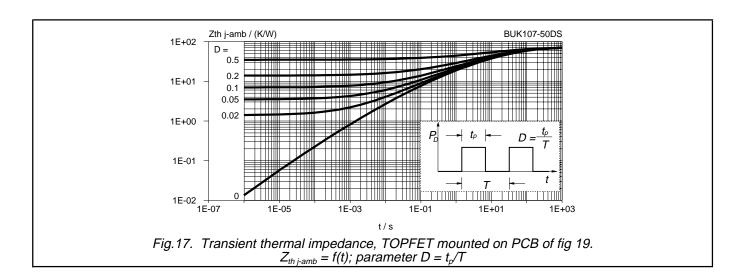
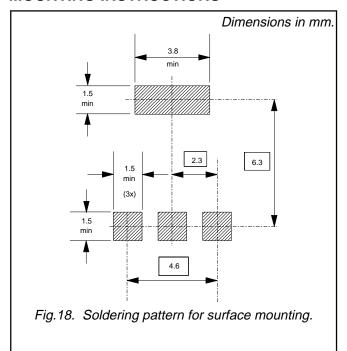


Fig.15. Typical switching waveforms, resistive load . $R_L = 50~\Omega$; adjust V_{DD} to obtain $I_D = 250~\text{mA}$; $T_j = 25^\circ\text{C}$



MOUNTING INSTRUCTIONS



PRINTED CIRCUIT BOARD

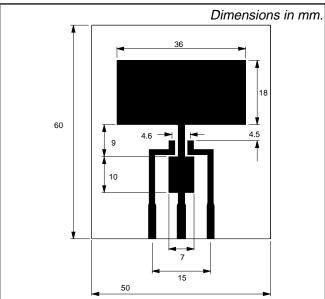
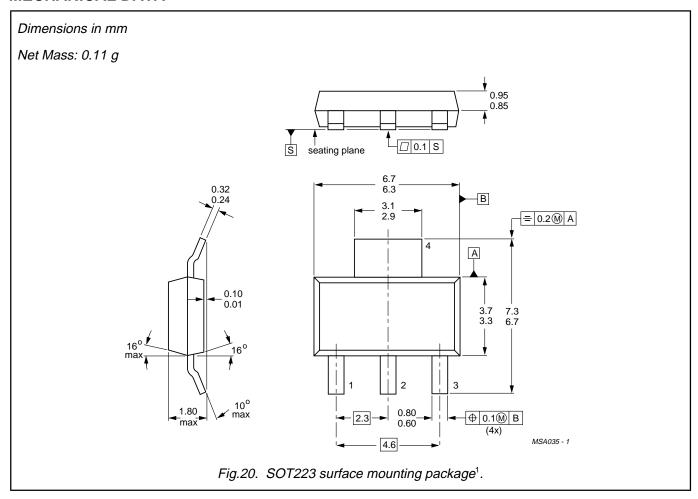


Fig.19. PCB for thermal resistance and power rating. PCB: FR4 epoxy glass (1.6 mm thick), copper laminate (35 μm thick).

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MECHANICAL DATA



¹ For further information, refer to surface mounting instructions for SOT223 envelope. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification This data sheet contains final product specifications.					

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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